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## **Bi-Directional Triode Thyristor**

# **Power Pac™ Triacs**

6A to 15A RMS Up to 600 Volts **Isolated and Non-isolated Tab** 

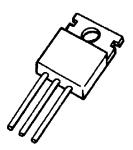
ISOLATED TAB
SC140
SC142
SC147
NON- ISOLATED TAB
SC141
SC143
SC146
SC149
SC151

#### **FEATURES:**

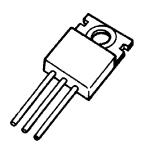
- POWER-GLASTM passivated silicon chip for maximum reliability.
- Very low off-state (leakage) current at room and elevated temperatures.
- Inherent immunity from non-repetitive transient voltage damage (max. critical rate-of-rise of on-state current subsequent to voltage breakover triggering,  $di/dt = 10 \text{ A}/\mu\text{sec.}$ ).
- · Low on-state voltage at high current levels.
- · Excellent surge current capability.
- 1600 volts RMS Surge Isolation Voltage on Isolated Triacs.
- · Selected types available from factory for use where circuit requires
  - with popular zero voltage triggering IC's
  - at 400 Hz
  - with low gate trigger current
  - at higher voltage levels
  - at higher commutating dv/dt levels

## **POWER PAC PACKAGE**

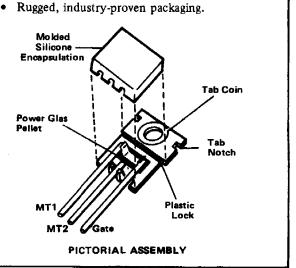
- Meets JEDEC TO-220AB specifications.
- Round leads greatly simplifies assembly.
- Six standard lead forming configurations available from factory (including TO-66 compatibility.)



ISOLATED (RED)



NON-ISOLATED (BLUE)

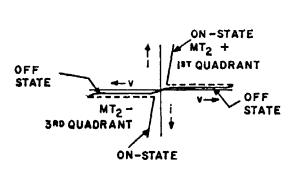


ISOLATED TAB	NON-ISOLATED TAB			
SC140, 2, 7	SC141, 3, 6, 9, SC151			

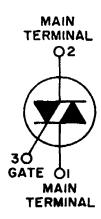
#### MAXIMUM ALLOWABLE RATINGS

TYPE	RMS ON-STATE CURRENT,	REPETITIVE PEAK OFF-STATE VOLTAGE, V <sub>DRM</sub> <sup>(2)</sup>				PEAK ONE FULL CYCLE SURGE (NON-REP) ON-STATE CURRENT, I <sub>TSM</sub> AMPERES		I <sup>2</sup> t FOR FUSING FOR TIMES AT(3)	
	IT(RMS) <sup>(1)</sup> AMPERES							(RMS AMPERE)2	(RMS AMPERE)2
		В	D	E	M	50 Hz	60 Hz	SECONDS 1.0	SECONDS, 8.3 MILLISECONDS
		VOLTS	VOLTS	VOLTS	VOLTS	AMPERES	AMPERES	MILLISECOND	
ISOLATE	D TAB								
SC140	6.5	200	400	500	600	74	80	18	26.5
SC142	8	200	400	500	600	104	110	20	50
SC147	10	200	400	500	600	104	110	20	50
NON-ISO	LATED TAB								
SC141	6	200	400	500	600	74	80	18	26.5
SC143	8	200	400	500	600	110	120	20	60
SC146	10	200	400	500	600	110	120	20	60
SC149	12	200	400	500	600	110	120	20	60
SC151	15	200	400	500	600	110	120	20	60

Peak Gate Power Dissipation, P <sub>GM</sub> (4)	10 Watts for 10 Microseconds (See Chart 4)
Average Gate Power Dissipation, P <sub>G(AV)</sub>	0.5 Watts
Peak Gate Current, I <sub>GM</sub> (4)	See Chart 4
Peak Gate Voltage, V <sub>GM</sub> (4)	
Storage Temperature, T <sub>stg</sub>	40°C to +125°C
Operating Temperature, T <sub>J</sub>	40 °C to +100 °C
Surge Isolation Voltage (5)	1600 Volts RMS



TYPICAL CHARACTERISTICS VOLT-AMPERES



TERMINAL ARRANGEMENT

### NOTES:

- 1. At the case reference point (see outline drawing) temperature of 80°C maximum (except 75°C maximum for SC142 and SC149) and 360° conduction.
- 2. Ratings apply for zero gate voltage only, Ratings apply for either polarity of main terminal 2 voltage referenced to main terminal 1.
- 3. Ratings apply for either polarity of main terminal 2 referenced to main terminal 1.
- 4. Ratings apply for either polarity of gate terminal referenced to main terminal 1.
- 5. Isolated tab triacs only. Rating applies from main terminals 1 and 2 and gate terminal to device mounting surface. Test voltage is 50 or 60 Hz sinusoidal wave form applied for one minute. Rating applies over the entire device operating temperature range.

ISOLATED TAB	NON-ISOLATED TAB			
SC140, 2, 7	SC141, 3, 6, 9, SC151			

## **CHARACTERISTICS**

TEST	SYMBOL	MIN.	TYP.	MAX.	UNITS	TEST CONDITIONS	REF. NOTE
Repetitive Peak Off- State Current	I <sub>DRM</sub>				mA	V <sub>DRM</sub> = Maximum Allowable Repeti- tive Off-State Voltage Rating Gate Open Circuited	1
				0.1	1	$T_C = +25$ °C	
		_	_	0.5	1	$T_{\rm C} = +100^{\circ}{\rm C}$	1
Peak On-State Voltage	$V_{TM}$				Volts	$T_C$ = +25°C, $I_{TM}$ = 1 msec., Wide Pulse, Duty Cycle $\leq$ 2%	1
SC140		_	_	1.85	1	$I_{TM} = 9.2 \text{ A Peak}$	7
SC141		_		1.83	1	I <sub>TM</sub> = 8.5 A Peak	1
SC142				1.75	1	I <sub>TM</sub> = 11.5 A Peak	
SC143				1.55	1	I <sub>TM</sub> = 11.5 A Peak	7
SC146		_		1.65	1	I <sub>TM</sub> = 14 A Peak	7
SC147			_	1.50	1	I <sub>TM</sub> = 14 A Peak	7
SC149		_		1.65	1	I <sub>TM</sub> = 17 A Peak	
SC151		~		1.52	1	I <sub>TM</sub> = 21 A Peak	7
Critical Rate-of-Rise of Off-State Voltage (Higher values may cause device switching)	dv/dt				Volts/µsec	T <sub>C</sub> = +100°C, Rated V <sub>DRM</sub> Gate Open Circuited Exponential Voltage Waveform	1
SC140, SC141		30	100	_	1		
SC142, SC143		50	150	T - T			
SC146, SC147		100	150	_	1		}
SC149		100	200	_	1		
SC151		100	250		]		
Critical Rate-of-Rise of Commutating Off-State Voltage (Commutating dv/dt)	dv/dt <sub>(c)</sub>	4		_	Volts/μsec	I <sub>T(RMS)</sub> = Rated Maximum Allow- able RMS On-State Current, V <sub>DRM</sub> = Maximum Rated Peak Off-State Voltage, Gate Open Circuited.	1, 4
DC Gate Trigger	$I_{GT}$				mAdc	V <sub>D</sub> = 12 Vdc	2
Current	0.			}		TRIGGER MODE RL TC	7
				50		MT2+ Gate + 100 Ohms	1
				50		MT2- Gate - 100 Ohms +25°C	
				50	-	MT2+ Gate - 50 Ohms	
		<del></del>		80	-	MT2+ Gate + 50 Ohms	7
	[		_	80	1	MT2- Gate - 50 Ohms -40°C	
		_		80	-	MT2+ Gate - 25 Ohms	
DC Gate Trigger	$v_{GT}$		<del>                                     </del>	<del>                                     </del>	Vdc	V <sub>D</sub> = 12 Vdc	2
Voltage	YGT				****	TRIGGER MODE RL TC	<b>-</b>
-				2.5	-	MT2+ Gate + 100 Ohms	-
			<del></del>	2.5	-	MT2- Gate - 100 Ohms +25°C	
			<del>                                     </del>	2.5	1	MT2+ Gate - 50 Ohms   125 C	
				3.5	-	MT2+ Gate + 50 Ohms	+
			<del>                                     </del>	3.5	-[	MT2- Gate - 50 Ohms -40°C	1
		<del> </del> _	<del>                                     </del>	3.5		MT2+ Gate - 25 Ohms	
DC Gate Non-Trigger	$V_{\mathrm{GD}}$	0.2	<del>                                     </del>	3.3	Vdc	TRIGGER MODE RL TC	2, 3
Voltage	'GD	0.2	_	_	Vac	MT2+ Gate +	1 2,3
. CITERO			1			MT2- Gate - 1000	
						+   00°C	
					İ	<u> </u>	1
	1	<u> </u>	1	l	1	MT2- Gate +	